

2SC4627

Silicon NPN epitaxial planar type

For high-frequency amplification

■ Features

- Optimum for RF amplification of FM/AM radios
- High frequency voltage f_T
- SS-Mini type package, allowing downsizing of the equipment and automatic insertion through the tape packing.

■ Absolute Maximum Ratings $T_a = 25^\circ\text{C}$

Parameter	Symbol	Rating	Unit
Collector-base voltage (Emitter open)	V_{CBO}	30	V
Collector-emitter voltage (Base open)	V_{CEO}	20	V
Emitter-base voltage (Collector open)	V_{EBO}	3	V
Collector current	I_{C}	15	mA
Collector power dissipation	P_{C}	125	mW
Junction temperature	T_{j}	125	$^\circ\text{C}$
Storage temperature	T_{stg}	-55 to +125	$^\circ\text{C}$

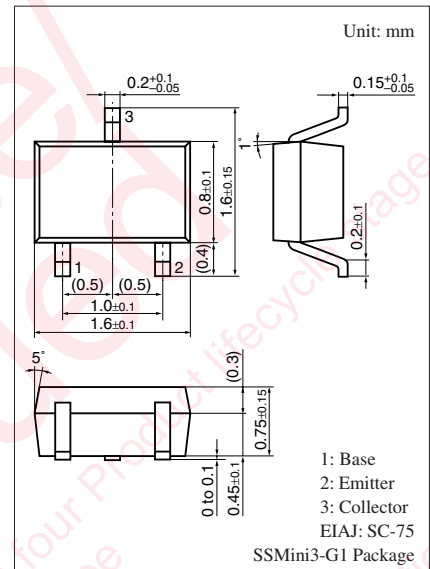
■ Electrical Characteristics $T_a = 25^\circ\text{C} \pm 3^\circ\text{C}$

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Collector-base voltage (Emitter open)	V_{CBO}	$I_{\text{C}} = 10 \mu\text{A}, I_{\text{E}} = 0$	30			V
Emitter-base voltage (Collector open)	V_{EBO}	$I_{\text{E}} = 10 \mu\text{A}, I_{\text{C}} = 0$	3			V
Base-emitter voltage	V_{BE}	$V_{\text{CB}} = 6 \text{ V}, I_{\text{E}} = -1 \text{ mA}$		0.72		V
Forward current transfer ratio *	h_{FE}	$V_{\text{CB}} = 6 \text{ V}, I_{\text{E}} = -1 \text{ mA}$	40		260	—
Transition frequency	f_{T}	$V_{\text{CB}} = 6 \text{ V}, I_{\text{E}} = -1 \text{ mA}, f = 200 \text{ MHz}$	450	650		MHz
Common-emitter reverse transfer capacitance	C_{re}	$V_{\text{CB}} = 6 \text{ V}, I_{\text{E}} = -1 \text{ mA}, f = 10.7 \text{ MHz}$		0.8	1	pF
Noise figure	NF	$V_{\text{CB}} = 6 \text{ V}, I_{\text{E}} = -1 \text{ mA}, f = 100 \text{ MHz}$		3.3		dB
Power gain	G_{P}	$V_{\text{CB}} = 6 \text{ V}, I_{\text{E}} = -1 \text{ mA}, f = 100 \text{ MHz}$		24		dB

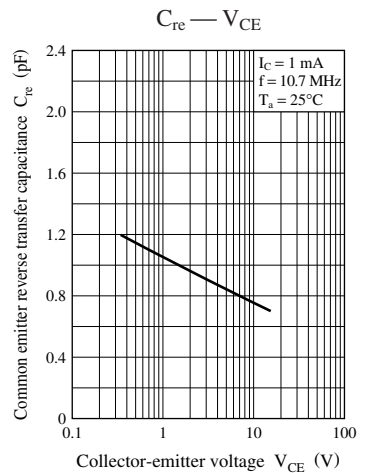
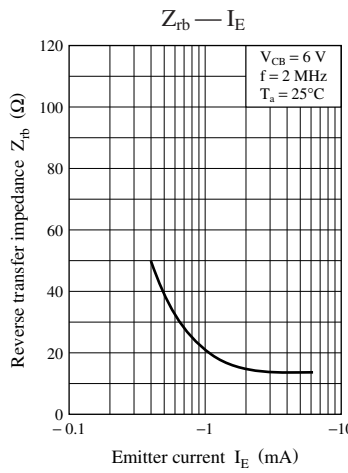
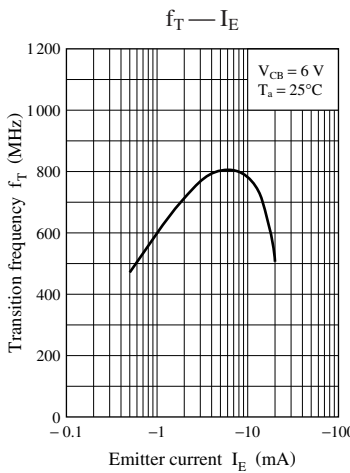
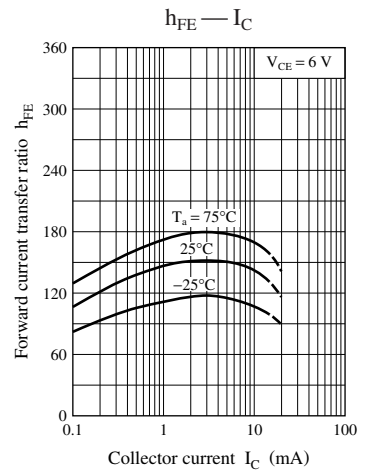
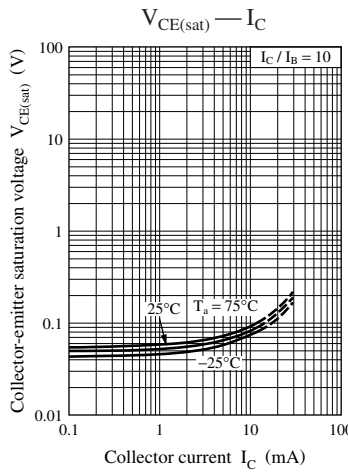
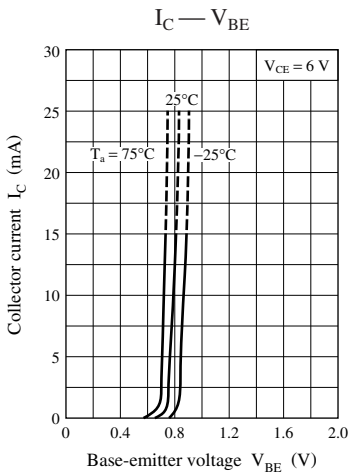
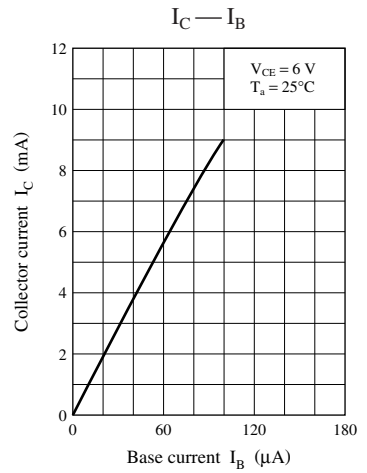
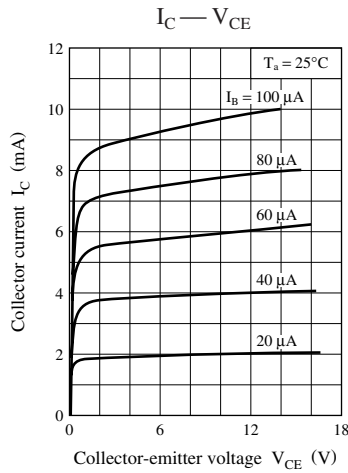
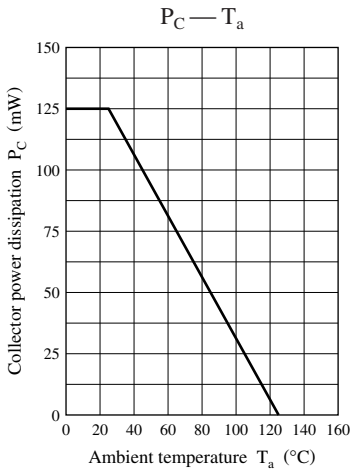
Note) 1. Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 measuring methods for transistors.

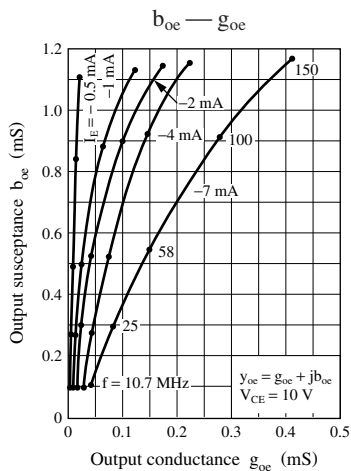
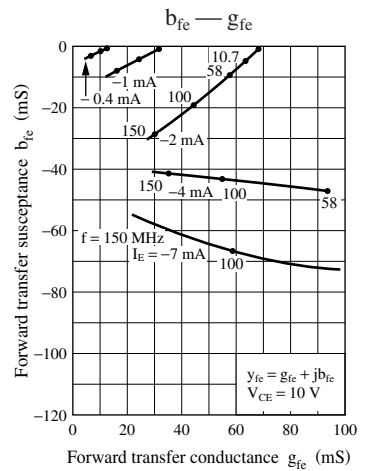
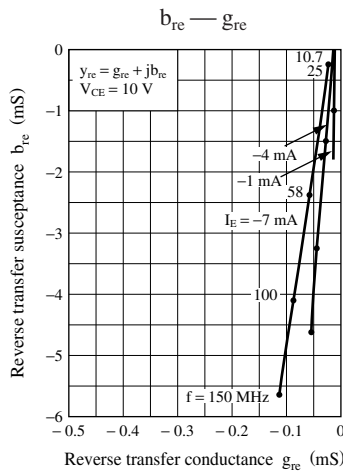
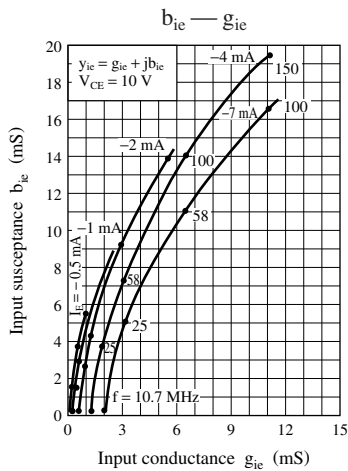
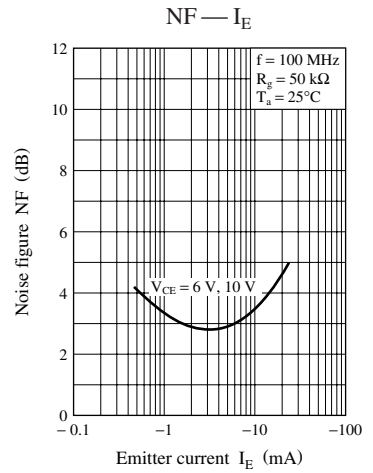
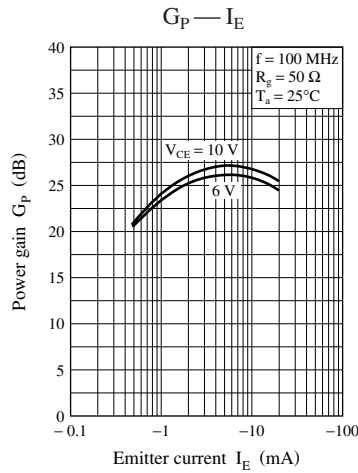
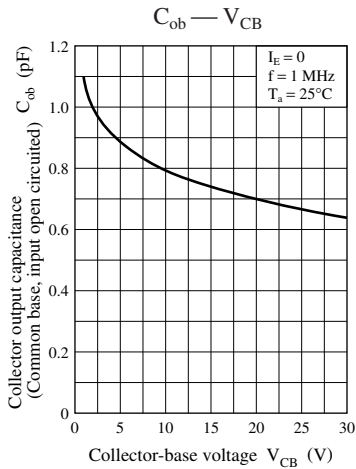
2. *: Rank classification

Rank	B	C	D
h_{FE}	40 to 110	65 to 160	100 to 260



Marking Symbol: U





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